

PC957L0NSZ

Photocoupler

High Speed and High CMR *OPIC Photocoupler

Features

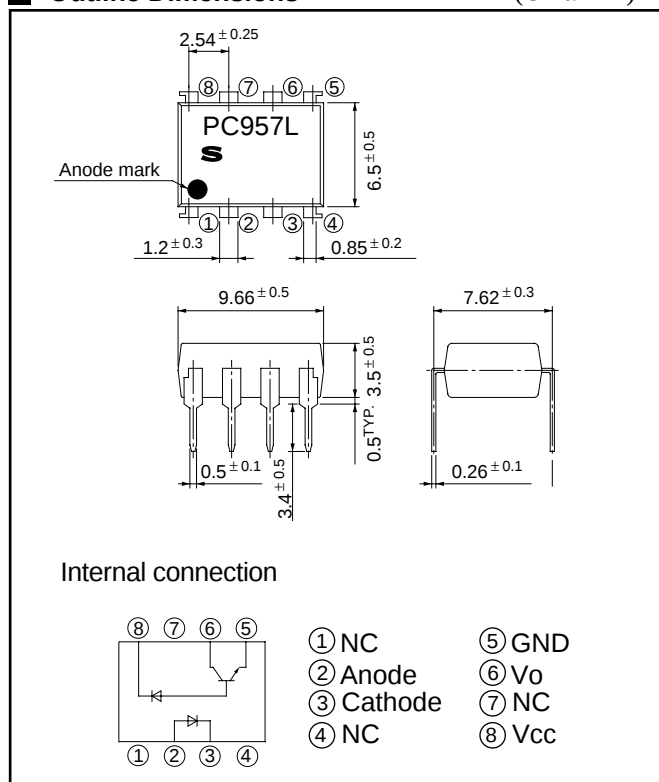
- (1) High instantaneous common mode rejection voltage (CMR:MIN. 15kV/ μ s)
- (2) High speed response
(t_{PHL} :MAX. 0.8 μ s, t_{PLH} :MAX. 0.8 μ s)
- (3) Isolation voltage($V_{iso}(rms)$: 5.0kV)
- (4) 8-pin DIP package
- (5) Flow soldering : 280°C for 6s or less
- (6) Recognized by UL (file No. E64380)
Under preparation for VDE standard

Applications

- (1) Programmable controller
- (2) Inverter

Outline Dimensions

(Unit: mm)



* "OPIC" (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	25	mA
	Reverse voltage	V_R	5	V
	Power dissipation	P	45	mW
Output	Supply voltage	V_{CC}	-0.5 to +30	V
	Output voltage	V_O	-0.5 to +20	V
	Output current	I_O	8	mA
	Power dissipation	P_O	100	mW
	*1 Isolation voltage	$V_{iso}(rms)$	5.0	kV
	Operating temperature	T_{opr}	-55 to +100	°C
	Storage temperature	T_{stg}	-55 to +125	°C
	*2 Soldering temperature	T_{sol}	270	°C

*1 40 to 60% RH, for 1 minute

*2 For 10s at the portion of 0.2mm or more from the root of lead pins

(Notice)

•In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

•Specifications are subject to change without notice for improvement.

(Internet)

•Data for Sharp's optoelectronic/power devices is provided on internet. (Address <http://sharp-world.com/ecg/>)

Electro-optical Characteristics

(Ta=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$I_F=16\text{mA}$	—	1.7	1.95	V
	Reverse current	I_R	$V_R=5\text{V}$	—	—	10	μA
	Terminal capacitance	C_t	$V_F=0, f=1\text{MHz}$	—	60	250	pF
Output	High level output current	$I_{OH(1)}$	$I_F=0, V_{CC}=5.5\text{V}$ $V_O=5.5\text{V}$	—	3	500	nA
		$I_{OH(2)}$	$I_F=0, V_{CC}=15\text{V}, V_O=15\text{V}$	—	0.01	1.0	μA
		$I_{OH(3)}$	$I_F=0, V_{CC}=15\text{V}, V_O=15\text{V} *3$	—	—	50	
	High level supply current	$I_{CCH(1)}$	$I_F=0, V_{CC}=15\text{V}, V_O=\text{OPEN}$	—	0.02	1.0	μA
		$I_{CCH(2)}$	$I_F=0, V_{CC}=15\text{V}, V_O=\text{OPEN} *3$	—	—	2.0	
	Low level supply current	I_{CCL}	$I_F=16\text{mA}, V_{CC}=15\text{V},$ $V_O=\text{OPEN}$	—	120	—	μA
	Low level output voltage	V_{OL}	$I_F=16\text{mA}, V_{CC}=4.5\text{V},$ $I_O=2.4\text{mA}$	—	0.1	0.4	V
Transfer characteristics	Current transfer ratio	CTR(1)	$I_F=16\text{mA}, V_{CC}=4.5\text{V}, V_O=0.4\text{V}$	19	—	50	%
		CTR(2)	$I_F=16\text{mA}, V_{CC}=4.5\text{V}, V_O=0.4\text{V} *3$	15	—	—	
	Isolation resistance	R_{ISO}	DC500V, 40 to 60%RH	5×10^{10}	10^{11}	—	Ω
	Floating capacitance	C_f	$V=0\text{V}, f=1\text{MHz}$	—	0.6	1.0	pF
	"High→Low" transfer time	t_{PHL}	$I_F=16\text{mA}, V_{CC}=5\text{V}$ $R_L=1.9\text{k}\Omega$	—	0.2	0.8	μs
	"Low→High" transfer time	t_{PLH}		—	0.6	0.8	
	Instantaneous common mode rejection voltage "Output: High level"	CM_H	$I_F=0\text{mA}, R_L=1.9\text{k}\Omega,$ $V_{CM}=1.0\text{kV}_{P-P},$ $V_{CC}=5\text{V}$	15	30	—	kV/ μs
	Instantaneous common mode rejection voltage "Output: Low level"	CM_L	$I_F=16\text{mA}, R_L=1.9\text{k}\Omega,$ $V_{CM}=1.0\text{kV}_{P-P},$ $V_{CC}=5\text{V}$	−15	−30	—	kV/ μs

*3 Ta=0 to 70°C